

July 1994 Revised April 1999

74VHC27

Triple 3-Input NOR Gate

General Description

The VHC27 is an advanced high speed CMOS 3-Input NOR Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This cir-

cuit prevents device destruction due to mismatched supply and input voltages.

Features

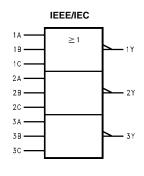
- High speed: $t_{PD} = 4.1$ ns (typ) at $T_A = 25$ °C
- Low power dissipation: $I_{CC} = 2 \mu A \text{ (max)}$ at $T_A = 25^{\circ}C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC27

Ordering Code:

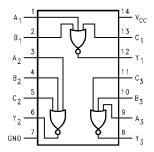
| Order Number | Package Number | Package Description | | | | | |
|--------------|----------------|---|--|--|--|--|--|
| 74VHC27M | M14A | 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow | | | | | |
| 74VHC27SJ | M14D | 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide | | | | | |
| 74VHC27MTC | MTC14 | 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide | | | | | |
| 74VHC27N | N14A | 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide | | | | | |

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

| Pin Names | Description | | | | |
|-----------------|-------------|--|--|--|--|
| A_n, B_n, C_n | Inputs | | | | |
| Y _n | Outputs | | | | |

Truth Table

| Α | В | С | Υ |
|---|---|---|---|
| Н | Х | Х | L |
| Х | Н | Х | L |
| Х | Х | Н | L |
| L | L | L | Н |

X = Don't Care

Absolute Maximum Ratings(Note 1)

DC V $_{\rm CC}$ /GND Current (I $_{\rm CC}$) ± 50 mA Storage Temperature (T $_{\rm STG}$) $-65^{\circ}{\rm C}$ to $+150^{\circ}{\rm C}$

Lead Temperature (T_L)

(Soldering, 10 seconds) 260°C

Recommended Operating Conditions (Note 2)

Input Rise and Fall Time (t_r, t_f)

$$\begin{split} \text{V}_{\text{CC}} &= 3.3 \text{V} \pm 0.3 \text{V} & \text{0 ns/V} \sim 100 \text{ ns/V} \\ \text{V}_{\text{CC}} &= 5.0 \text{V} \pm 0.5 \text{V} & \text{0 ns/V} \sim 20 \text{ ns/V} \end{split}$$

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

| Symbol | Parameter | V _{CC} (V) | T _A = 25°C | | | $T_A = -40^{\circ}C$ to $+85^{\circ}C$ | | Units | Conditions | |
|-----------------|-----------------------------|------------------------|-----------------------|-----|-------------------------------|--|------------------|-------|-------------------------------|--------------------------|
| | | | Min | Тур | Max | Min | Max | Onits | Cond | itions |
| V _{IH} | HIGH Level | 2.0 | 1.50 | | | 1.50 | | V | | |
| | Input Voltage | 3.0 – 5.5 | 0.7 V _{CC} | | | 0.7 V _{CC} | | V | | |
| V _{IL} | LOW Level | 2.0 | | | 0.50 | | 0.50 | V | | |
| | Input Voltage | 3.0 - 5.5 | | | $0.3\mathrm{V}_{\mathrm{CC}}$ | | $0.3 V_{\rm CC}$ | v | | |
| V _{OH} | HIGH Level | 2.0 | 1.9 | 2.0 | | 1.9 | | | $V_{IN} = V_{IH}$ | $I_{OH} = -50 \mu A$ |
| | Output Voltage | 3.0 | 2.9 | 3.0 | | 2.9 | | V | or V _{IL} | |
| | | 4.5 | 4.4 | 4.5 | | 4.4 | | | | |
| | | 3.0 | 2.58 | | | 2.48 | | V | | $I_{OH} = -4 \text{ mA}$ |
| | | 4.5 | 3.94 | | | 3.80 | | v | | $I_{OH} = -8 \text{ mA}$ |
| V _{OL} | LOW Level | 2.0 | | 0.0 | 0.1 | | 0.1 | | $V_{IN} = V_{IH}$ | $I_{OL} = 50 \mu A$ |
| | Output Voltage | 3.0 | | 0.0 | 0.1 | | 0.1 | V | or V _{IL} | |
| | | 4.5 | | 0.0 | 0.1 | | 0.1 | | | |
| | | 3.0 | | | 0.36 | | 0.44 | V | | I _{OL} = 4 mA |
| | | 4.5 | | | 0.36 | | 0.44 | v | | $I_{OL} = 8 \text{ mA}$ |
| I _{IN} | Input Leakage Current | 0 – 5.5 | | | ±0.1 | | ±1.0 | μΑ | V _{IN} = 5.5V or GND | |
| I _{CC} | Quiescent Supply Current | 5.5 | | | 2.0 | | 20.0 | μА | $V_{IN} = V_{CC}$ or 0 | GND |

Noise Characteristics

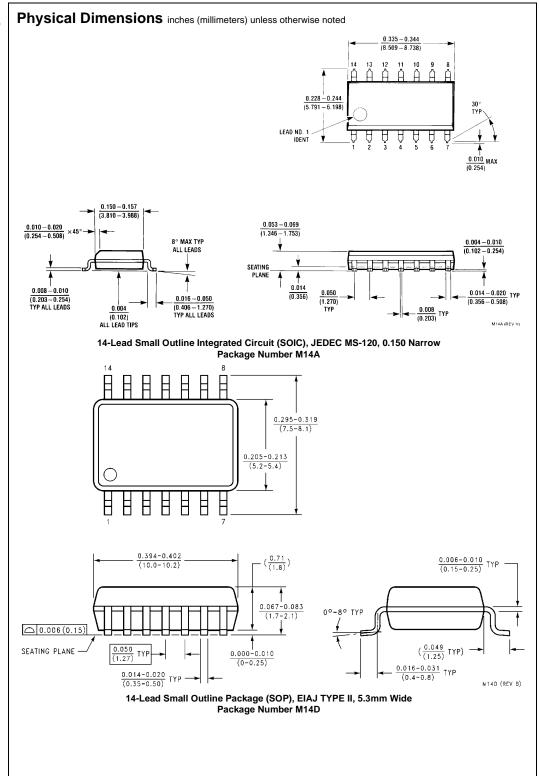
| Symbol | Parameter | V _{CC} (V) | TA | = 25°C | Units | Conditions | |
|------------------|-------------------------|------------------------|------|--------|-------|------------------------|--|
| | | | Тур | Limits | | Conditions | |
| V _{OLP} | Quiet Output Maximum | 5.0 | 0.3 | 0.8 | V | C _L = 50 pF | |
| (Note 3) | Dynamic V _{OL} | | | | | | |
| V _{OLV} | Quiet Output Minimum | 5.0 | -0.3 | -0.8 | V | C _L = 50 pF | |
| (Note 3) | Dynamic V _{OL} | | | | | | |
| V_{IHD} | Minimum HIGH Level | 5.0 | | 3.5 | V | C _L = 50 pF | |
| (Note 3) | Dynamic Input Voltage | | | | | | |
| V _{ILD} | Maximum LOW Level | 5.0 | | 1.5 | V | C _L = 50 pF | |
| (Note 3) | Dynamic Input Voltage | | | | | | |

Note 3: Parameter guaranteed by design.

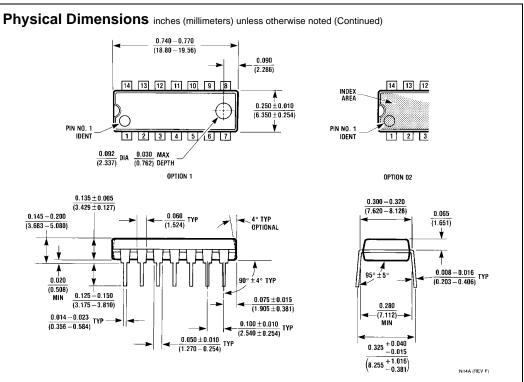
AC Electrical Characteristics

| Symbol | Parameter | V _{CC} | T _A = 25°C | | | $T_A = -40^{\circ}C$ to $+85^{\circ}C$ | | Units | Conditions |
|------------------|-------------------|-----------------|-----------------------|-----|------|--|------|-------|------------------------|
| | | (V) | Min | Тур | Max | Min | Max | Onito | Conditions |
| t _{PHL} | Propagation Delay | 3.3 ± 0.3 | | 6.2 | 8.8 | 1.0 | 10.5 | ns | C _L = 15 pF |
| t _{PLH} | | | | 8.7 | 12.3 | 1.0 | 14.0 | 115 | C _L = 50 pF |
| | | 5.0 ± 0.5 | | 4.1 | 5.9 | 1.0 | 7.0 | ns | C _L = 15 pF |
| | | | | 5.6 | 7.9 | 1.0 | 9.0 | 115 | C _L = 50 pF |
| C _{IN} | Input Capacitance | | | 4 | 10 | | 10 | pF | V _{CC} = Open |
| C _{PD} | Power Dissipation | | | 20 | | | | pF | (Note 4) |
| | Capacitance | | | | | | | | |

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/3 (per gate).



Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 5.0±0.1 0.43 TYP -A-7.72 4.16 6.4 4.4±0.1 -B-3.2 -0.42 ALL LEAD TIPS LAND PATTERN RECOMMENDATION PIN #1 IDENT. SEE DETAIL A ALL LEAD TIPS 0.90+0.15 1.2 MAX [0.09-0.20 -C-L_{0.10±0.05} 0.65 412.00°ТОР & ВОТТОМ R0.16 R0.31-GAGE PLANE NDTES: 0.25 A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION ABJREF NOTE 6, DATED 7/930°-8° B. DIMENSIONS ARE IN MILLIMETERS C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS 0.6±0.1 SEATING PLANE -1.00-DETAIL A 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide Package Number N14A

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